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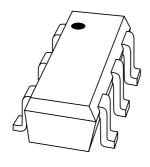
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DISCRETE SEMICONDUCTORS

DATA SHEET



PUMF11 NPN resistor-equipped transistor; PNP general purpose transistor

Product data sheet 2002 Apr 09



NPN resistor-equipped transistor; PNP general purpose transistor

PUMF11

FEATURES

- Resistor-equipped transistor and general purpose transistor in one package
- 100 mA collector current
- 50 V collector-emitter voltage
- 300 mW total power dissipation
- SOT363 package; replaces two SOT323 (SC-70) packaged devices on same PCB area
- · Reduced pick and place costs.

APPLICATIONS

- Power management switch for portable equipment, e.g. cellular phone and CD player
- · Switch for regulator.

DESCRIPTION

NPN resistor-equipped transistor and a PNP general purpose transistor in a SOT363 (SC-88) plastic package.

MARKING

TYPE NUMBER	MARKING CODE(1)
PUMF11	R1*

Note

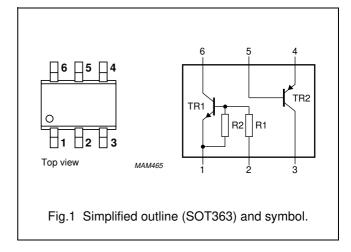
- 1. * = p: Made in Hong Kong.
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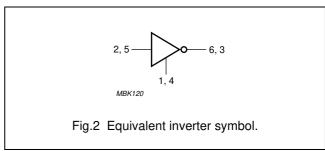
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT	
TR1 (NPN)				
V _{CEO}	collector-emitter voltage	50	V	
Io	output current (DC)	100	mA	
R1	bias resistor	22	kΩ	
R2	bias resistor	47	kΩ	
TR2 (PNP)				
V _{CEO}	collector-emitter voltage	50	V	
I _C	collector current (DC)	100	mA	
I _{CM}	peak collector current 200 mA		mA	

PINNING

PIN	DESCRIPTION		
1, 4	emitter	TR1; TR2	
2, 5	base	TR1; TR2	
6, 3	collector	TR1; TR2	





NPN resistor-equipped transistor; PNP general purpose transistor

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

PARAMETER	CONDITIONS	MIN.	MAX.	UNIT			
Per transistor							
total power dissipation	T _{amb} ≤ 25 °C; note 1	_	200	mW			
storage temperature		-65	+150	°C			
junction temperature		_	150	°C			
operating ambient temperature		-65	+150	°C			
	·						
collector-base voltage	open emitter	_	50	V			
collector-emitter voltage	open base	_	50	V			
emitter-base voltage open collector		_	10	V			
input voltage							
positive		_	+40	V			
negative		_	-10	V			
output current (DC)		_	100	mA			
peak collector current		_	100	mA			
collector-base voltage	open emitter	_	-50	V			
collector-emitter voltage	open base	_	-40	V			
emitter-base voltage	open collector	_	-5	V			
collector current (DC)		_	-100	mA			
peak collector current		-	-200	mA			
		<u> </u>	•	•			
total power dissipation	T _{amb} ≤ 25 °C; note 1	_	300	mW			
	total power dissipation storage temperature junction temperature operating ambient temperature collector-base voltage collector-emitter voltage emitter-base voltage input voltage positive negative output current (DC) peak collector current collector-base voltage collector-base voltage collector current	total power dissipation	total power dissipation	total power dissipation			

Note

1. Device mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	in free air; note 1	416	K/W

Note

1. Device mounted on an FR4 printed-circuit board.

NPN resistor-equipped transistor; PNP general purpose transistor

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CHARACTERISTICS

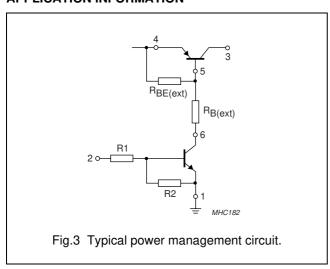
 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
TR1 (NPN)						
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0	_	_	100	nA
I _{CEO}	collector-emitter cut-off current	V _{CE} = 30 V; I _B = 0	_	-	1	μΑ
		$V_{CE} = 30 \text{ V}; I_{B} = 0; T_{j} = 150 ^{\circ}\text{C}$	_	-	50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0$	_	-	0.12	mA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 5 mA	80	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	_	-	150	mV
$V_{i(off)}$	input off voltage	$V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$	_	0.9	0.5	٧
V _{i(on)}	input on voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 2 \text{ mA}$	2	1.1	_	٧
R1	input resistor		15.4	22	28.6	kΩ
R2 R1	resistor ratio		1.7	2.1	2.6	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0; f = 1 \text{ MHz}$	_	-	2.5	рF
TR2 (PNP)						
I _{CBO}	collector-base cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0$	_	-	-100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CB} = -30 \text{ V}; I_B = 0; T_j = 150 \text{ °C}$	_	_	-10	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -4 \text{ V}; I_C = 0$	_	_	-100	nA
h _{FE}	DC current gain	$V_{CE} = -6 \text{ V}; I_{C} = -1 \text{ mA}$	120	_	_	
V _{CEsat}	saturation voltage	$I_C = -50 \text{ mA}$; $I_B = -5 \text{ mA}$; note 1	_	_	-200	mV
C _c	collector capacitance	$V_{CB} = -12 \text{ V}; I_E = i_e = 0; f = 1 \text{ MHz}$	_	_	2.2	рF
f _T	transition frequency	$V_{CE} = -12 \text{ V}; I_{C} = -2 \text{ mA}; f = 100 \text{ MHz}$	100	_	_	MHz

Note

1. Device mounted on an FR4 printed-circuit board.

APPLICATION INFORMATION



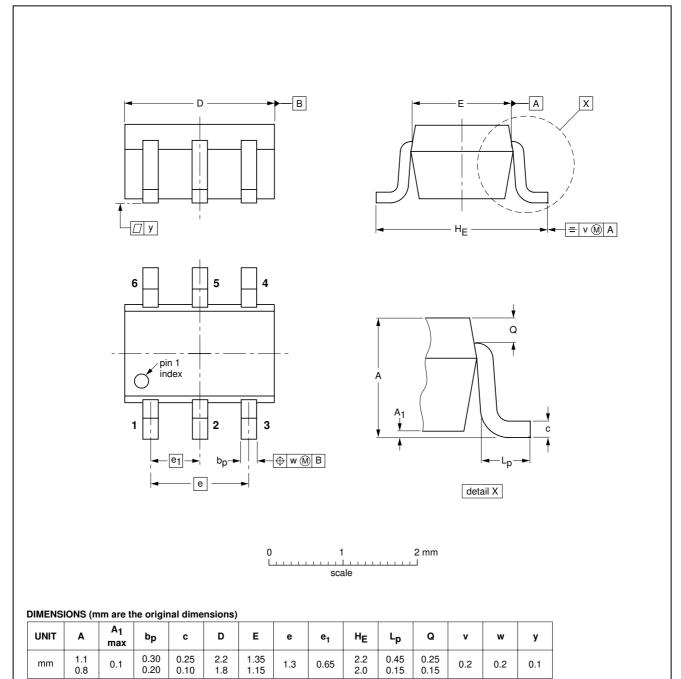
NPN resistor-equipped transistor; PNP general purpose transistor

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PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT363



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION ISSUE DATE	
SOT363			SC-88			97-02-28

NPN resistor-equipped transistor; PNP general purpose transistor

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DATA SHEET STATUS

DOCUMENT STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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NXP Semiconductors

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Contact information

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